WHAT IS CLAIMED IS:

1. An organometallic iridium compound represented by the following general formula (1):

$$R^{7}$$

$$R^{6}$$

$$R^{6}$$

$$R^{5}$$

$$R^{4}$$

$$R^{1}$$

$$R^{1}$$

$$R^{1}$$

$$R^{1}$$

$$R^{1}$$

$$R^{2}$$

$$R^{1}$$

$$R^{2}$$

$$R^{3}$$

$$R^{2}$$

$$R^{3}$$

$$R^{2}$$

$$R^{3}$$

$$R^{4}$$

$$R^{5}$$

wherein R¹ represents hydrogen or a lower alkyl group; and R², R³, R⁴, R⁵, R⁶, and R⁷ are the same or different and each represents hydrogen, a halogen, a lower acyl group, a lower alkoxy group, a lower alkoxycarbonyl group, or a lower alkyl group, provided that the case where all of R¹, R², R³, R⁴, R⁵, R⁶, and R⁷ represent hydrogen is excluded.

2. An organometallic iridium compound represented by the following general formula (2):

$$R^{10}$$
 R^{10}
 R^{11}
 R^{12}
 R^{12}
 R^{10}
 R^{10}
 R^{10}
 R^{10}
 R^{10}
 R^{10}
 R^{10}
 R^{10}
 R^{10}
 R^{10}

wherein R⁸ represents a lower alkyl group; and R⁹, R¹⁰, R¹¹, and R¹² are the same or different and each represents hydrogen, a halogen, a lower acyl group, a lower alkoxy group, a lower alkoxycarbonyl group, or a lower alkyl group, provided that the case where R⁸, R⁹, and R¹¹ each represents a methyl group, and R¹⁰ and R¹² each represents

hydrogen is excluded.

3. A process of producing an organometallic iridium compound represented by the following general formula (1), which comprises reacting an iridium compound, a cyclohexadiene derivative represented by the following general formula (3), and a cyclopentadiene derivative represented by following general formula (4):

$$R^{7}$$

$$R^{6}$$

$$R^{5}$$

$$R^{4}$$

$$R^{1}$$

$$R^{1}$$

$$R^{1}$$

$$R^{1}$$

$$R^{1}$$

$$R^{2}$$

$$R^{1}$$

$$R^{2}$$

$$R^{3}$$

$$R^{2}$$

$$R^{3}$$

$$R^{2}$$

$$R^{3}$$

$$R^{4}$$

$$R^{5}$$

wherein R¹ represents hydrogen or a lower alkyl group; R², R³, R⁴, R⁵, R⁶, and R⁷ are the same or different and each represents hydrogen, a halogen, a lower acyl group, a lower alkoxy group, a lower alkoxycarbonyl group, or a lower alkyl group, provided that the case where all of R¹, R², R³, R⁴, R⁵, R⁶, and R⁷ represent hydrogen is excluded; and M represents an alkali metal.

4. A process of producing an organometallic iridium compound represented by the following general formula (2), which comprises reacting an iridium compound, a butadiene derivative represented by the following general formula (5), and a cyclopentadiene derivative represented by following general formula (6):

$$R^{10}$$
 R^{9}
 R^{8}
 R^{11}
 R^{12}
(2)

$$R^{10}$$
 R^{11}
 R^{12}
(5)

wherein R⁸ represents a lower alkyl group; R⁹, R¹⁰, R¹¹, and R¹² are the same or different and each represents hydrogen, a halogen, a lower acyl group, a lower alkoxy group, a lower alkoxycarbonyl group, or a lower alkyl group, provided that the case where R⁸, R⁹, and R¹¹ each represents a methyl group, and R¹⁰ and R¹² each represents hydrogen is excluded; and M represents an alkali metal.

5. A process of producing an iridium-containing thin film, which comprises using, as a precursor, an organometallic iridium compound represented by the following

general formula (1):

wherein R¹ represents hydrogen or a lower alkyl group, and R², R³, R⁴, R⁵, R⁶, and R⁷ are the same or different and each represents hydrogen, a halogen, a lower acyl group, a lower alkoxy group, a lower alkoxycarbonyl group, or a lower alkyl group, provided that the case where all of R¹, R², R³, R⁴, R⁵, R⁶, and R⁷ represent hydrogen is excluded.

6. A process of producing an iridium-containing thin film, which comprises using, as a precursor, an organometallic iridium compound represented by the following general formula (2):

$$R^{10}$$
 R^{10}
 R^{11}
 R^{12}
 R^{12}
 R^{10}
 R^{10}

wherein R⁸ represents a lower alkyl group; and R⁹, R¹⁰, R¹¹, and R¹² are the same or different and each represents hydrogen, a halogen, a lower acyl group, a lower alkoxy group, a lower alkoxycarbonyl group, or a lower alkyl group, provided that the case where R⁸, R⁹, and R¹¹ each represents a methyl group, and R¹⁰ and R¹² each represents hydrogen is excluded.

- 7. The process as claimed in claim 5, which comprises using the CVD process.
- 8. The process as claimed in claim 6, which comprises using the CVD process.